

BRCS060N04ZCQ

Rev.B Mar.-2025

/ Descriptions

PDFN5×6 N

N-Channel MOSFET in a PDFN5x6 Plastic Package.

/ Features

$V_{DS}(V)=40V$ $I_D=60A$

$R_{DS(ON)}@10V \leq 6m\Omega$ (Typ. 5.6m Ω)

$R_{DS(ON)}@4.5V \leq 9m\Omega$ (Typ.7.8m Ω)

AEC-Q101

Qualified to AEC-Q101 Standards for High Reliability,

HF Product.

/ Applications

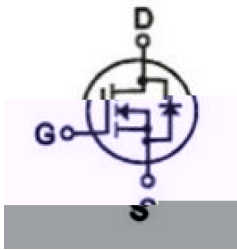
MB/NB/UMPC/VGA

Buck

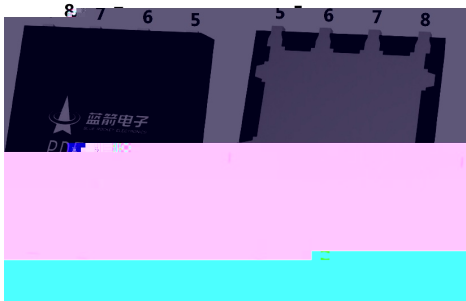
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Battery Management, High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA, Networking DC-DC Power System, Load Switch, Meet the stringent requirements of automotive applications.

/ Equivalent Circuit



/ Pinning



PIN1 2 3 S PIN4 G PIN5 6 7 8 D

/ Marking

See Marking Instructions.

/ Absolute Maximum Ratings($T_a=25$)

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	V_{DSS}	40	V	
Drain Current	$I_D(T_c=25)$	60	A	
Drain Current - Pulsed	I_{DM}	120	A	
Gate-Source Voltage	V_{GS}	± 20	V	
Single Pulsed Avalanche Energy	E_{AS}	300	mJ	
Avalanche Current	I_{AS}	24.5	A	
Power Dissipation	$P_D(T_c=25)$	37	W	
Operating and Storage Temperature Range	T_J, T_{stg}	-55 to 150		
Thermal resistance, junction - ambient	t = 10s	R_{JA}	25	/ W
	Steady-State		55	
Thermal resistance, junction - case	Steady-State	R_{JC}	3.4	

/ Electrical Characteristics($T_a=25$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=250\mu A$	40	46		V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=40V$ $V_{GS}=0V$			1	μA
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=0V$			± 0.1	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	1.0	1.6	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=20A$		5.6	6	$m\Omega$
		$V_{GS}=4.5V$ $I_D=10A$		7.8	9	$m\Omega$
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=1A$			1.2	V
Input Capacitance	C_{iss}	$V_{DS}=25V$ $V_{GS}=0V$ $f=1.0MHz$		2200		pF
Output Capacitance	C_{oss}			265		
Reverse Transfer Capacitance	C_{rss}			145		
Gate resistance	R_g	$V_{GS}=0V$ $f=1MHz$ $V_{DS}=0V$		2.1		Ω
Total Gate Charge	$Q_{g(10V)}$	$V_{GS}=10V$ $V_{DS}=20V$ $I_D=20A$		41		nC
Total Gate Charge	$Q_{g(4.5V)}$			9.8		
Gate Source Charge	Q_{gs}			4.2		
Gate Drain Charge	Q_{gd}			4.9		

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=20V$ $I_D=20A$ $R_{GEN}=3.3\Omega$		11		ns
Turn-On Rise Time	t_r			69		
Turn-Off Delay Time	$t_{d(off)}$			39		
Turn-Off Fall Time	t_f			9.3		

/ Electrical Characteristic Curve

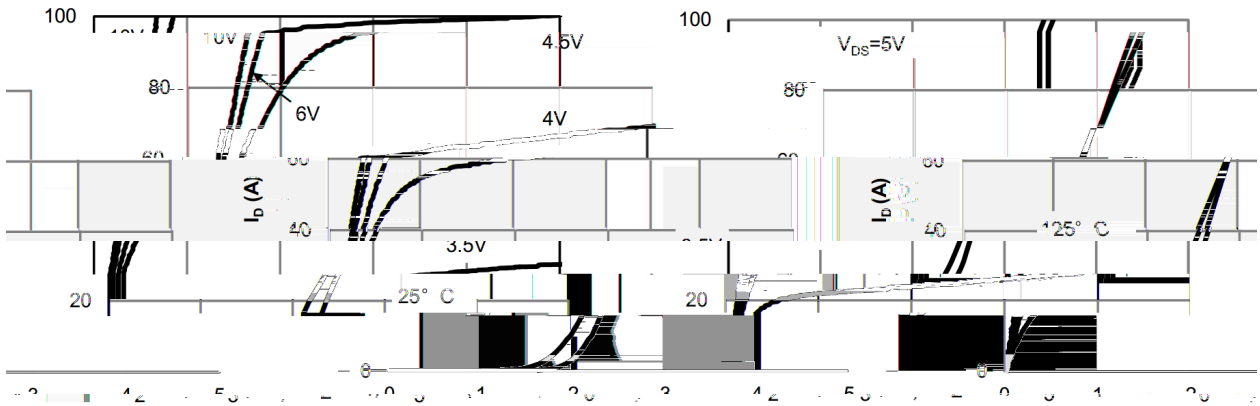


Figure 1: On-Region Characteristics

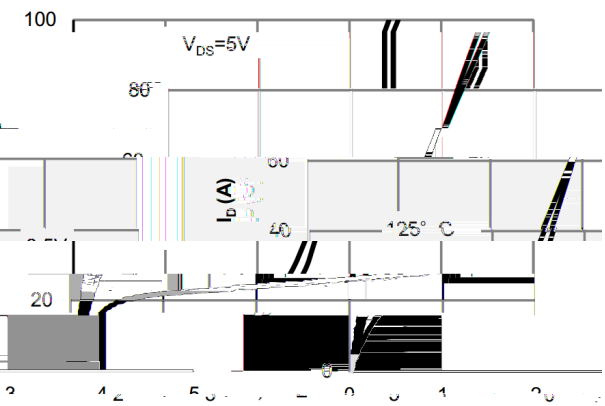


Figure 2: Transfer Characteristics

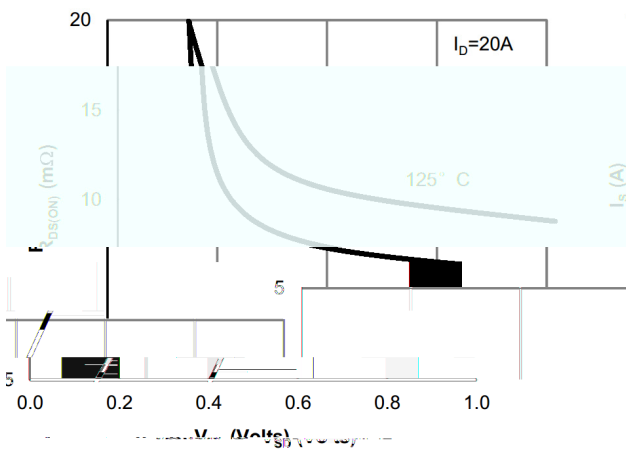
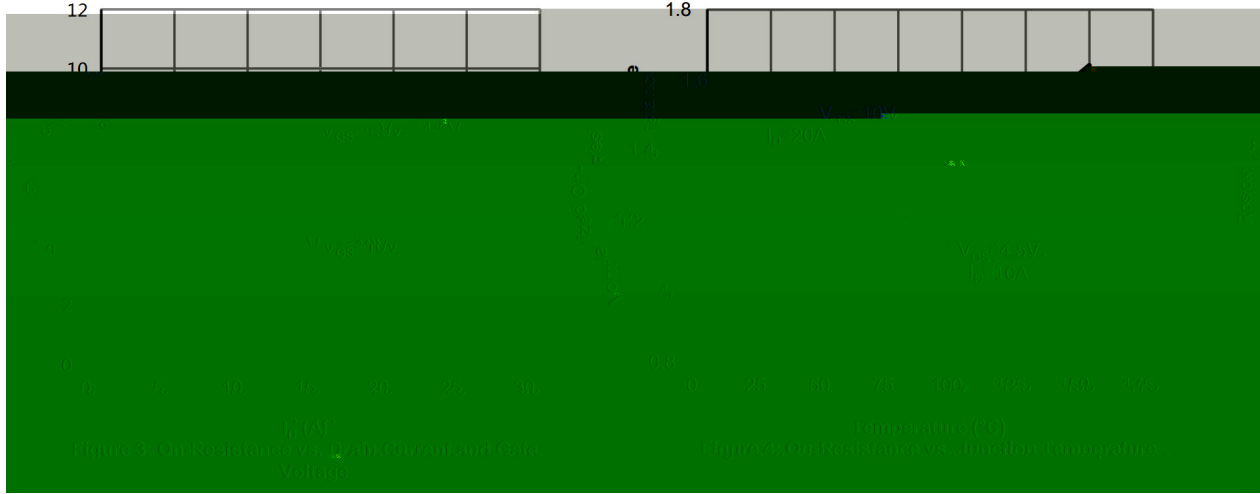


Figure 6: Body-Diode Characteristics

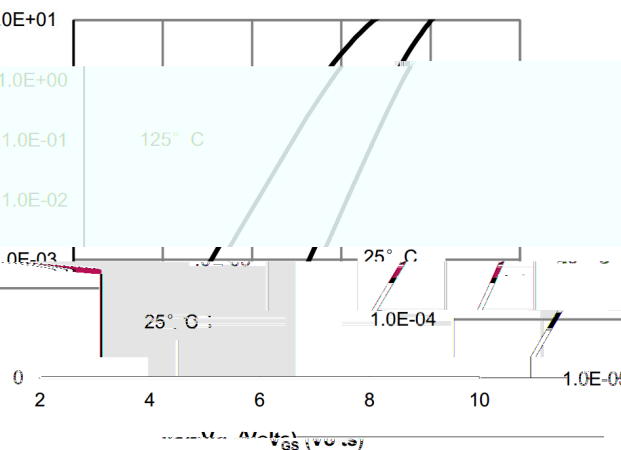
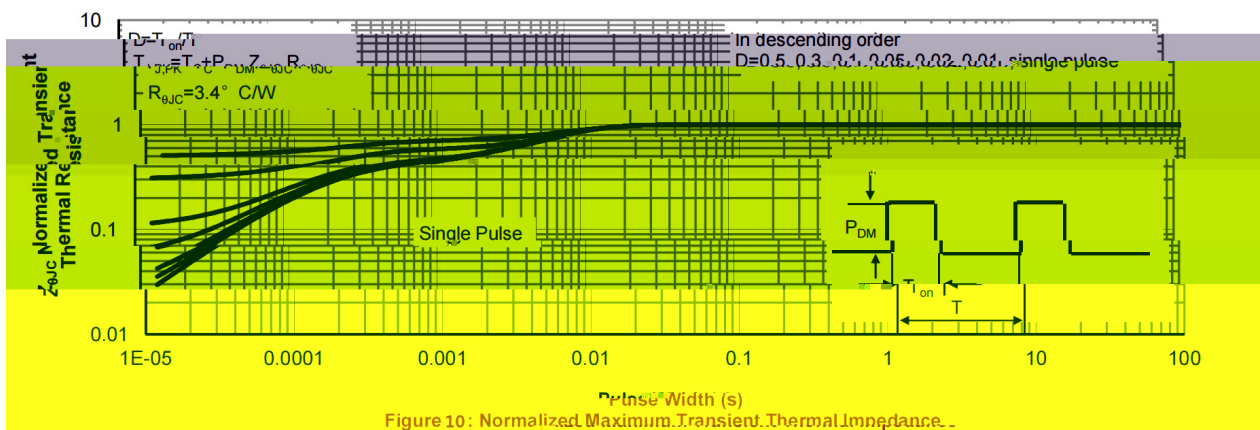
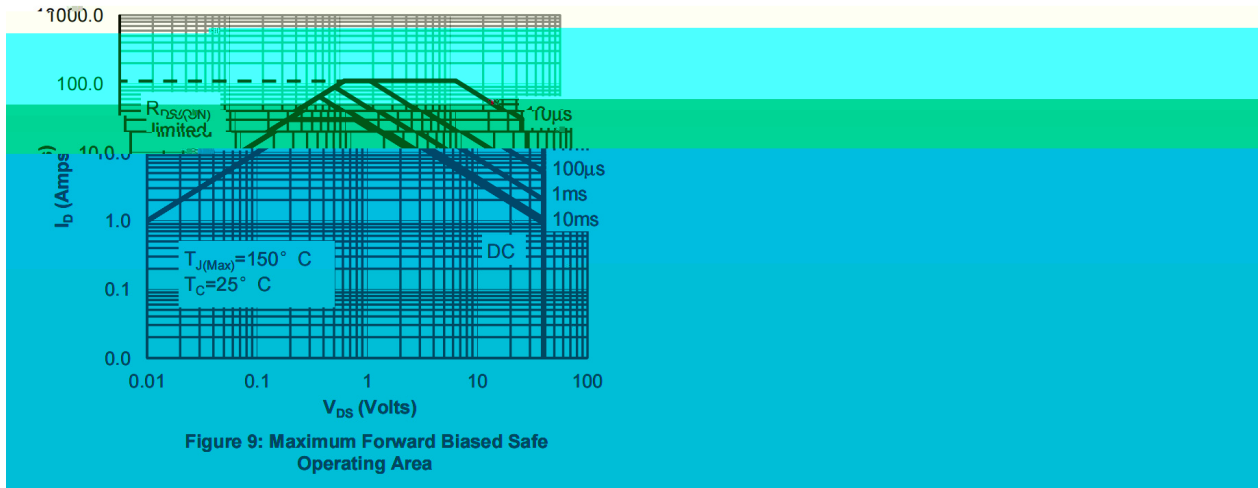
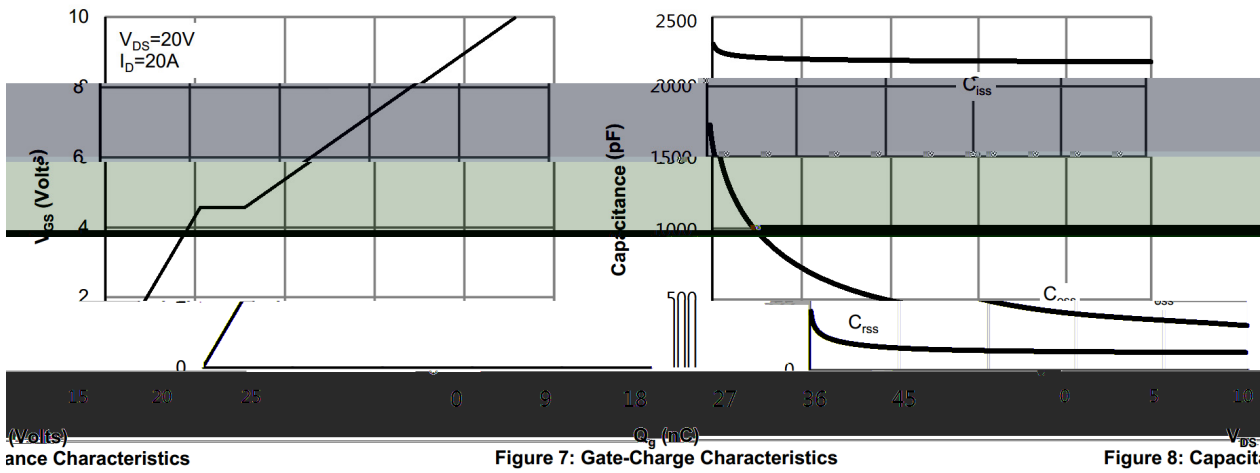


Figure 5: On-Resistance vs. Gate-Source Voltage

/ Electrical Characteristic Curve



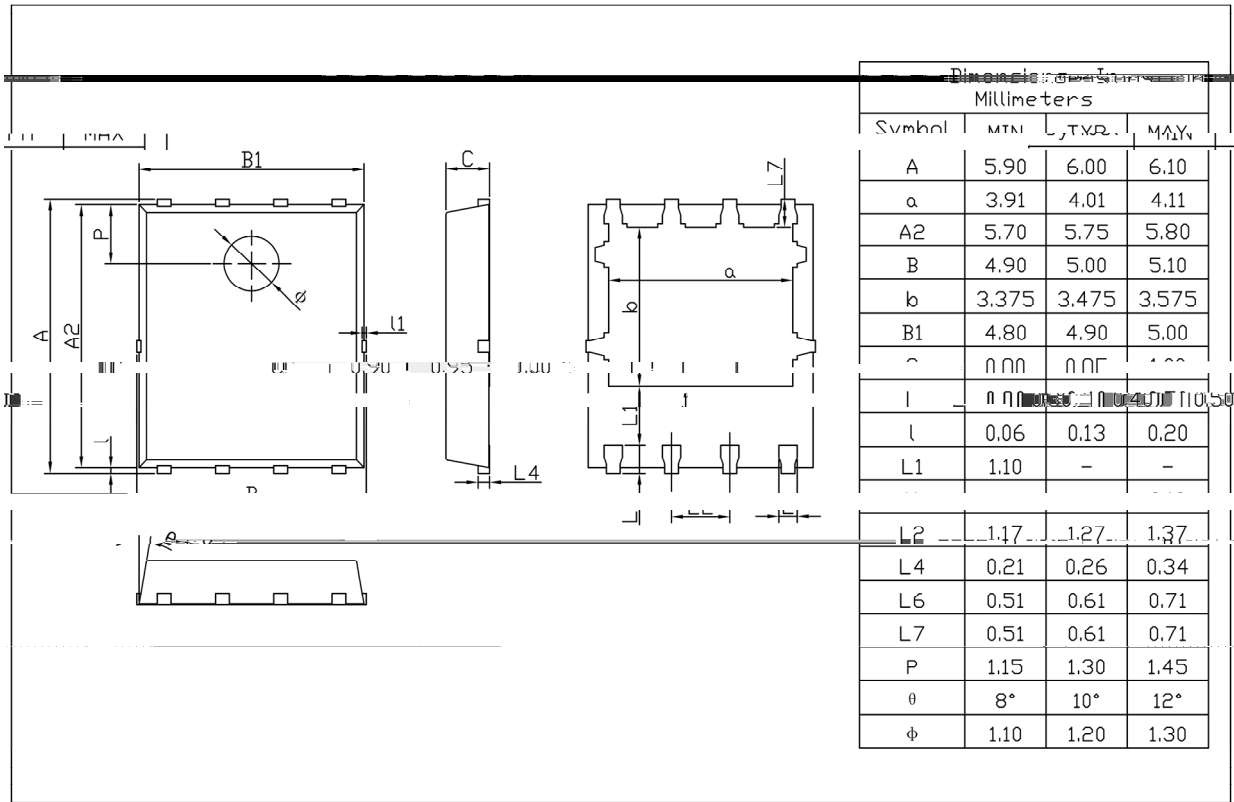
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/ Package Dimensions

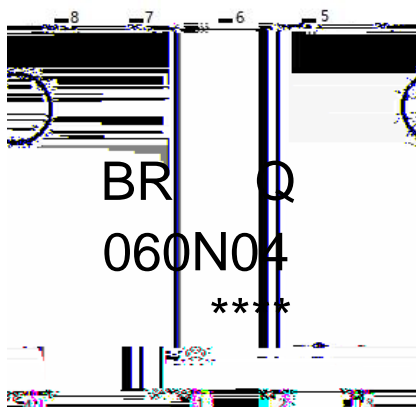
PDFN5 X6

Unit:mm



Rev.01 202209

/ Marking Instructions



BR

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060N04

Note

BR

Company Code

Q:

Automobile halogen-free product Code

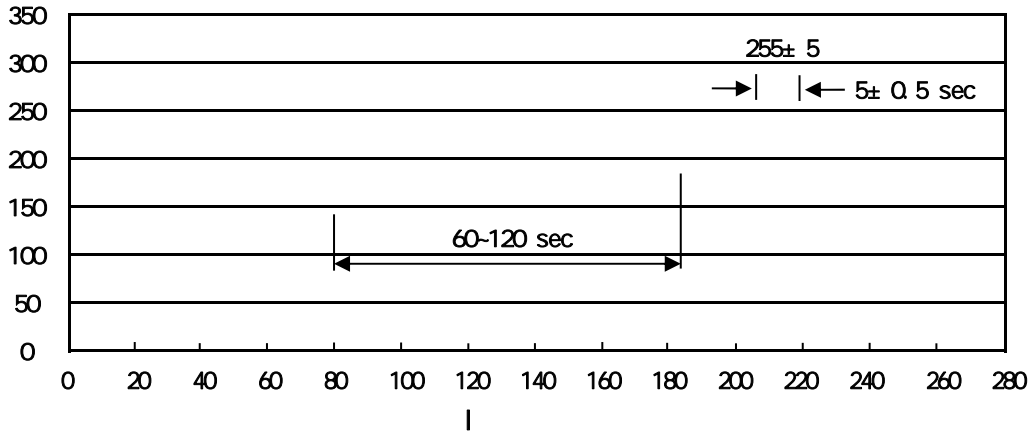
060N04

Product Type Code

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Lot No. Code, code change with Lot No

() / Temperature Profile for IR Reflow Soldering(Pb-Free)



- Note:
1. Preheating: 150~200 , Time: 60~120sec.
 2. Peak Temp.: 255±5 , Duration: 5±0.5sec.
 3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. 50 Temp.: 260±5 Time: 10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension (unit mm ³)		
	/	/	/	/	/			
PDFN5x6	5,000	2	10,000	6	60,000	13"x12	360x360x50	380x335x366

/ Notices